

Very High Slew Rate, Wideband Operational Amplifier

July 1994

Features

- This Circuit is Processed in Accordance to MIL-STD-883 and is Fully Conformant Under the Provisions of Paragraph 1.2.1.
- Supply Current 15.0mA (Max)
- Low Offset Voltage 2.0mV (Max)
- Very High Slew Rate 600V/ μ s (Typ)
- Open Loop Gain 20kV/V (Min)
- Wide Gain-Bandwidth ($A_v \geq 10$) 600MHz (Typ)
- Input Noise Voltage at 1kHz 6nV/ $\sqrt{\text{Hz}}$ (Typ)
- Enhanced Replacement for HA-2539/883 and EL2039

Applications

- Pulse and Video Amplifiers
- Wideband Amplifiers
- RF/IF Signal Processing
- High Speed Sample-Hold Circuits
- Fast, Precise D/A Converters
- RF Oscillators

Description

The HA-2839/883 is a wideband, very high slew rate, operational amplifier featuring superior speed and bandwidth characteristics. It also features trimmed supply current, which minimizes supply current (and thus A.C. parameter) variation over process and temperature extremes. For example, the I_{CC} variation over the entire military temperature range is typically less than 0.5mA. Bipolar construction, coupled with dielectric isolation, delivers outstanding performance in circuits with closed loop gains ≥ 10 .

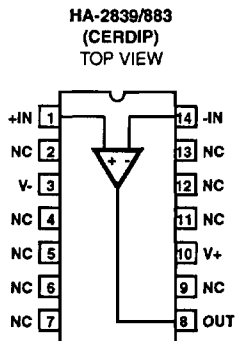
The 600V/ μ s slew rate, and 600MHz gain bandwidth product ensure high performance in video and wideband amplifier designs. Differential gain and phase are a low 0.03% and 0.03 degrees, respectively, making the HA-2839/883 ideal for video applications. A full $\pm 10V$ output swing, high open loop gain, and outstanding A.C. parameters make the HA-2839/883 an excellent choice for data acquisition systems.

Ordering Information

PART NUMBER	TEMPERATURE RANGE	PACKAGE
HA1-2839/883	-55°C to +125°C	14 Lead CerDIP

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Pinout



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Absolute Maximum Ratings

Voltage between V+ and V- Terminals	35V
Differential Input Voltage	6V
Voltage at Either Input Terminal	V+ to V-
Peak Output Current ($\leq 10\%$ Duty Cycle)	50mA
Junction Temperature (T_J)	+175°C
Storage Temperature Range	-65°C to +150°C
ESD Rating	<2000V
Lead Temperature (Soldering 10 seconds)	+300°C

Thermal Information

Thermal Resistance	θ_{JA}	θ_{JC}
14 Lead CerDIP Package	81°C/W	26°C/W
Package Power Dissipation Limit at +75°C for $T_J \leq +175^\circ\text{C}$		
14 Lead CerDIP Package	1.23W	
Package Power Dissipation Derating Factor Above +75°C		
14 Lead CerDIP Package	.12.3mW/°C	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Operating Conditions

Operating Temperature Range	-55°C to +125°C	$V_{INCM} \leq 1/2 (V+ - V-)$
Operating Supply Voltage	$\pm 12\text{V to } \pm 15\text{V}$	$R_L \geq 1\text{k}\Omega$

TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS

Device Tested at: $V_{SUPPLY} = \pm 15\text{V}$, $R_{SOURCE} = 100\Omega$, $R_{LOAD} = 100\text{k}\Omega$, $V_{OUT} = 0\text{V}$, Unless Otherwise Specified.

DC PARAMETERS	SYMBOL	CONDITIONS	GROUP A SUBGROUP	TEMPERATURE	LIMITS		UNITS
					MIN	MAX	
Input Offset Voltage	V_{IO}	$V_{CM} = 0\text{V}$	1	+25°C	-2	2	mV
			2, 3	+125°C, -55°C	-6	6	mV
Input Bias Current	+ I_B	$V_{CM} = 0\text{V}$, $+R_S = 1.1\text{k}\Omega$ $-R_S = 100\Omega$	1	+25°C	-14.5	14.5	μA
			2, 3	+125°C, -55°C	-20	20	μA
	- I_B	$V_{CM} = 0\text{V}$, $+R_S = 100\Omega$ $-R_S = 1.1\text{k}\Omega$	1	+25°C	-14.5	14.5	μA
			2, 3	+125°C, -55°C	-20	20	μA
Input Offset Current	I_{IO}	$V_{CM} = 0\text{V}$, $+R_S = 1.1\text{k}\Omega$ $-R_S = 1.1\text{k}\Omega$	1	+25°C	-4	4	μA
			2, 3	+125°C, -55°C	-8	8	μA
Common Mode Range	+CMR	$V+ = 5\text{V}$ $V- = -25\text{V}$	1	+25°C	10	-	V
			2, 3	+125°C, -55°C	10	-	V
	-CMR	$V+ = 25\text{V}$ $V- = -5\text{V}$	1	+25°C	-	-10	V
			2, 3	+125°C, -55°C	-	-10	V
Large Signal Voltage Gain	+ A_{VOL}	$V_{OUT} = 0\text{V}$ and +10V $R_L = 1\text{k}\Omega$	4	+25°C	20	-	kV/V
			5, 6	+125°C, -55°C	10	-	kV/V
	- A_{VOL}	$V_{OUT} = 0\text{V}$ and -10V $R_L = 1\text{k}\Omega$	4	+25°C	20	-	kV/V
			5, 6	+125°C, -55°C	10	-	kV/V
Common Mode Rejection Ratio	+CMRR	$\Delta V_{CM} = 10\text{V}$, $V_{OUT} = -10\text{V}$ $V+ = 5\text{V}$, $V- = -25\text{V}$	1	+25°C	75	-	dB
			2,3	+125°C, -55°C	75	-	dB
	-CMRR	$\Delta V_{CM} = -10\text{V}$, $V_{OUT} = 10\text{V}$ $V+ = 25\text{V}$, $V- = -5\text{V}$	1	+25°C	75	-	dB
			2, 3	+125°C, -55°C	75	-	dB

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TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS (Continued)

Device Tested at: $V_{SUPPLY} = \pm 15V$, $R_{SOURCE} = 100\Omega$, $R_{LOAD} = 100k\Omega$, $V_{OUT} = 0V$, Unless Otherwise Specified.

DC PARAMETERS	SYMBOL	CONDITIONS	GROUP A SUBGROUP	TEMPERATURE	LIMITS		UNITS
					MIN	MAX	
Output Voltage Swing	+ V_{OUT}	$R_L = 1k\Omega$	1	+25°C	10	-	V
			2, 3	+125°C, -55°C	10	-	V
	- V_{OUT}	$R_L = 1k\Omega$	1	+25°C	-	-10	V
			2, 3	+125°C, -55°C	-	-10	V
Output Current	+ I_{OUT}	$V_{OUT} = 10V$	1	+25°C	10	-	mA
			2, 3	+125°C, -55°C	10	-	mA
	- I_{OUT}	$V_{OUT} = -10V$	1	+25°C	-	-10	mA
			2, 3	+125°C, -55°C	-	-10	mA
Quiescent Power Supply Current	+ I_{CC}	$V_{OUT} = 0V$ $I_{OUT} = 0mA$	1	+25°C	-	14.6	mA
			2, 3	+125°C, -55°C	-	15	mA
	- I_{CC}	$V_{OUT} = 0V$ $I_{OUT} = 0mA$	1	+25°C	-14.6	-	mA
			2, 3	+125°C, -55°C	-15	-	mA
Power Supply Rejection Ratio	+PSRR	$\Delta V_{SUP} = 10V$ $V_+ = 10V, V_- = -15V$ $V_+ = 20V, V_- = -15V$	1	+25°C	75	-	dB
			2, 3	+125°C, -55°C	75	-	dB
	-PSRR	$\Delta V_{SUP} = 10V$ $V_+ = 15V, V_- = -10V$ $V_+ = 15V, V_- = -20V$	1	+25°C	75	-	dB
			2, 3	+125°C, -55°C	75	-	dB

TABLE 2. AC ELECTRICAL PERFORMANCE CHARACTERISTICS

Table 2 Intentionally Left Blank. See A.C. Specifications in Table 3

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TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS

Device Characterized at: $V_{SUPPLY} = \pm 15V$, $R_{SOURCE} = 50\Omega$, $R_{LOAD} = 1k\Omega$, $C_L \leq 10pF$, $A_V = +10V/V$, Unless Otherwise Specified.

PARAMETERS	SYMBOL	CONDITIONS	NOTES	TEMPERATURE	LIMITS		UNITS
					MIN	MAX	
Gain Bandwidth Product	GBWP	$V_O = 200mV$, $f_O = 5MHz$	1	+25°C	500	-	MHz
		$V_O = 200mV$, $f_O = 45MHz$	1	+25°C	450	-	MHz
Slew Rate	+SR	$V_O = -5V$ to +5V	1, 4	+25°C	550	-	V/ μ s
	-SR	$V_O = +5V$ to -5V	1, 4	+25°C	500	-	V/ μ s
Full Power Bandwidth	FPBW	$V_{PEAK} = 10V$	1, 2	+25°C	8.0	-	MHz
Rise and Fall Time	T_R	$V_O = 0V$ to +200mV	1, 4	+25°C	-	10	ns
	T_F	$V_O = 0V$ to -200mV	1, 4	+25°C	-	10	ns
Minimum Closed Loop Stable Gain	CLSG	$R_L = 1k\Omega$, $C_L \leq 10pF$	1	-55°C to +125°C	10	-	V/V
Overshoot	+OS	$V_O = 0V$ to +200mV	1	+25°C	-	30	%
	-OS	$V_O = 0V$ to -200mV	1	+25°C	-	30	%
Open Loop Output Resistance	R_{OUT}	$V_{OUT} = 0V$	1	+25°C	-	60	Ω
Quiescent Power Consumption	PC	$V_{OUT} = 0V$, $I_{OUT} = 0mA$	1, 3	-55°C to +125°C	-	450	mW

NOTES:

1. Parameters listed in Table 3 are controlled via design or process parameters and are not directly tested at final production. These parameters are lab characterized upon initial design release, or upon design changes. These parameters are guaranteed by characterization based upon data from multiple production runs which reflect lot to lot and within lot variation.
2. Full Power Bandwidth guarantee based on Slew Rate measurement using $FPBW = Slew\ Rate / (2\pi V_{PEAK})$.
3. Quiescent Power Consumption based upon Quiescent Supply Current test maximum. (No load on outputs.)
4. Measured between 10% and 90% points.

TABLE 4. ELECTRICAL TEST REQUIREMENTS

MIL-STD-883 TEST REQUIREMENTS	SUBGROUPS (SEE TABLE 1)
Interim Electrical Parameters (Pre Burn-In)	1
Final Electrical Test Parameters	1 (Note 1), 2, 3, 4, 5, 6
Group A Test Requirements	1, 2, 3, 4, 5, 6
Groups C & D Endpoints	1

NOTE:

1. PDA applies to Subgroup 1 only.

Die Characteristics

DIE DIMENSIONS:

65 x 52 x 19 mils ± 1 mils
 1650 x 1310 x 483µm ± 25.4µm

METALLIZATION:

Type: Aluminum, 1% Copper
 Thickness: 16kÅ ± 2kÅ

GLASSIVATION:

Type: Al, 1% Cu
 Silox Thickness: 12kÅ ± 2kÅ
 Nitride Thickness: 3.5kÅ ± 1kÅ

WORST CASE CURRENT DENSITY:

1.3 x 10⁵ A/cm² at 3.4mA

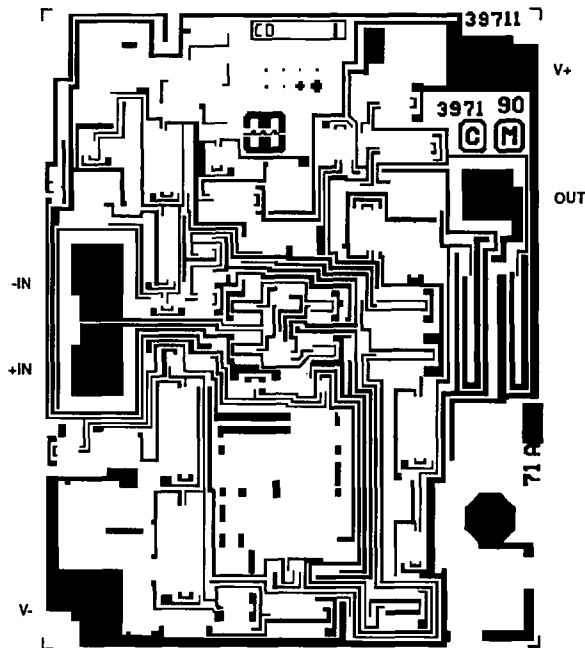
SUBSTRATE POTENTIAL (Powered Up): V-

TRANSISTOR COUNT: 34

PROCESS: Bipolar Dielectric Isolation

Metallization Mask Layout

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